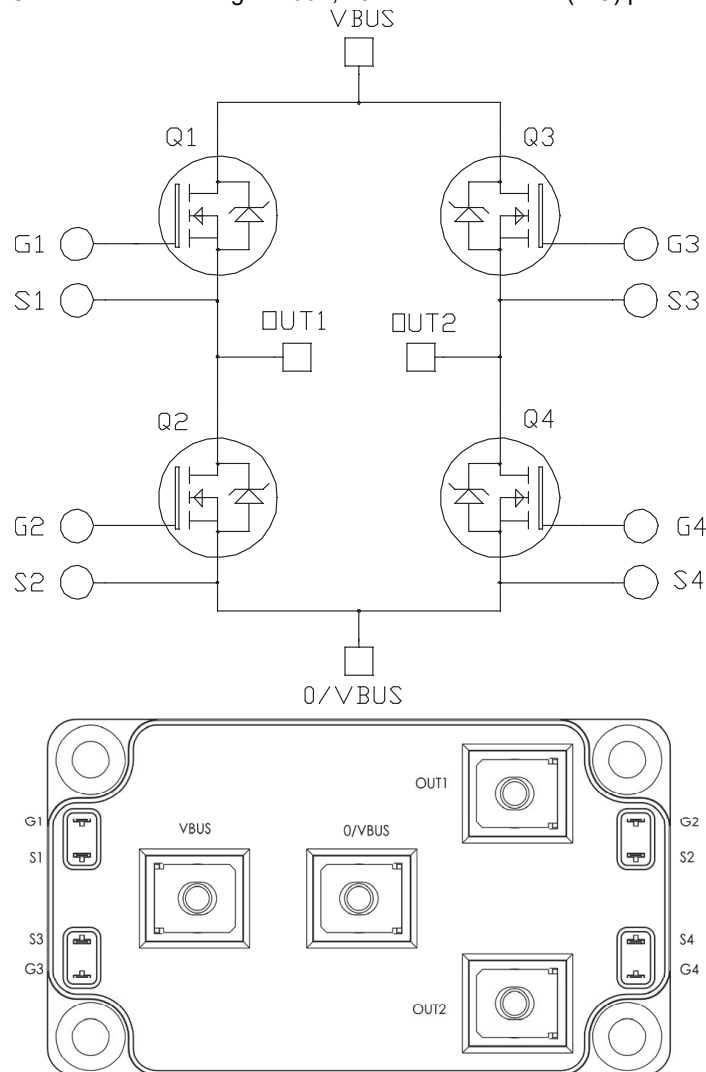


Full Bridge SiC Power Module

Product Overview

The MSCSM120HM083AG device is a full bridge 1200V, 251A silicon carbide (SiC) power module.



Note: All ratings at $T_j = 25^\circ\text{C}$, unless otherwise specified.



These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are key features of the MSCSM120HM083AG device:

- SiC Power MOSFET
 - Low $R_{DS(on)}$
 - High temperature performance
- Kelvin source for easy drive
- Low stray inductance
- M5 power connectors
- Aluminum Nitride (AlN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM120HM083AG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Stable temperature behavior
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

Application

The MSCSM120HM083AG device is designed for the following applications:

- Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

1. Electrical Specifications

This section provides the electrical specifications of the MSCSM120HM083AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Maximum Ratings	Unit
V_{DSS}	Drain-Source voltage	1200	V
I_D	Continuous drain current	$T_C = 25\text{ }^\circ\text{C}$	251
		$T_C = 80\text{ }^\circ\text{C}$	200
I_{DM}	Pulsed drain current	500	
V_{GS}	Gate-Source voltage	-10/23	V
$R_{DS(on)}$	Drain-Source ON resistance	10.4	m Ω
P_D	Power dissipation	$T_C = 25\text{ }^\circ\text{C}$	1042

The following table lists the electrical characteristics per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit	
I_{DSS}	Zero gate voltage drain current	$V_{GS} = 0V$ $V_{DS} = 1200V$	—	30	300	μA	
$R_{DS(on)}$	Drain-Source on resistance	$V_{GS} = 20V$ $I_D = 120A$	$T_J = 25\text{ }^\circ\text{C}$	—	8.4	10.4	m Ω
			$T_J = 175\text{ }^\circ\text{C}$	—	13.4	—	
$V_{GS(th)}$	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 9\text{ mA}$	1.8	2.8	—	V	
I_{GSS}	Gate-Source leakage current	$V_{GS} = 20V; V_{DS} = 0V$	—	—	300	nA	

MSCSM120HM083AG

Electrical Specifications

The following table lists the dynamic characteristics per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit	
C_{iss}	Input capacitance	$V_{GS} = 0V$	—	9	—	nF	
C_{oss}	Output capacitance	$V_{DS} = 1000V$	—	0.81	—		
C_{rss}	Reverse transfer capacitance	$f = 1\text{ MHz}$	—	0.07	—		
Q_g	Total gate charge	$V_{GS} = -5V/20V$	—	696	—	nC	
Q_{gs}	Gate-Source charge	$V_{Bus} = 800V$	—	123	—		
Q_{gd}	Gate-Drain charge	$I_D = 120A$	—	150	—		
$T_{d(on)}$	Turn-on delay time	$V_{GS} = -5V/20V$	$T_J = 150\text{ }^\circ\text{C}$	—	66	—	ns
T_r	Rise time	$V_{Bus} = 600V$		—	74	—	
$T_{d(off)}$	Turn-off delay time	$I_D = 150A$		—	166	—	
T_f	Fall time	$R_{G(on)} = 9.4\Omega$ $R_{G(off)} = 3.6\Omega$		—	67	—	
E_{on}	Turn-on energy	$V_{GS} = -5V/20V$	$T_J = 150\text{ }^\circ\text{C}$	—	4.8	—	mJ
E_{off}	Turn-off energy	$V_{Bus} = 600V$ $I_D = 150A$ $R_{G(on)} = 9.4\Omega$ $R_{G(off)} = 3.6\Omega$		—	2.2	—	
R_{Gint}	Internal gate resistance		—	2	—	Ω	
R_{thJC}	Junction-to-case thermal resistance		—	—	0.144	$^\circ\text{C/W}$	

The following table lists the body diode ratings and characteristics per SiC MOSFET of the MSCSM120HM083AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
V_{SD}	Diode forward voltage	$V_{GS} = 0V; I_{SD} = 120A$	—	4	—	V
		$V_{GS} = -5V; I_{SD} = 120A$	—	4.2	—	
t_{rr}	Reverse recovery time	$I_{SD} = 120A; V_{GS} = -5V$	—	90	—	ns
Q_{rr}	Reverse recovery charge	$V_R = 800V; di_F/dt = 3000\text{ A}/\mu\text{s}$	—	1650	—	nC
I_{rr}	Reverse recovery current		—	41	—	A

1.2 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM120HM083AG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristics	Min.	Max.	Unit		
V_{ISOL}	RMS isolation voltage, any terminal to case $t = 1$ min, 50 Hz/60 Hz	4000	—	V		
T_J	Operating junction temperature range	-40	175	°C		
T_{JOP}	Recommended junction temperature under switching conditions	-40	$T_{Jmax}-25$			
T_{STG}	Storage temperature range	-40	125			
T_C	Operating case temperature	-40	125			
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package weight	—	300	g		

1.3 Typical SiC MOSFET Performance Curve

This section shows the typical SiC MOSFET performance curves of the MSCSM120HM083AG device.

Figure 1-1. Maximum Thermal Impedance

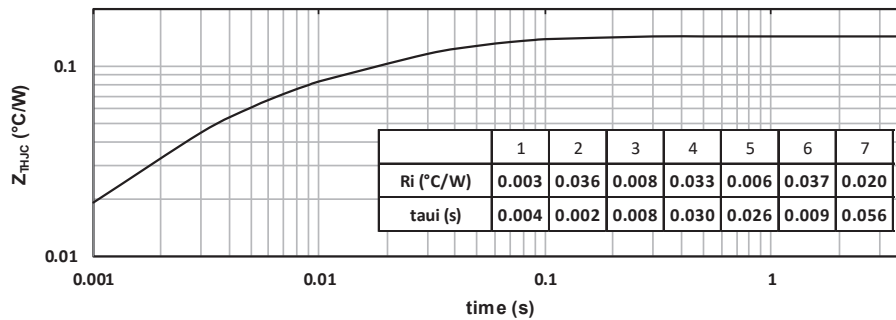


Figure 1-2. Output Characteristics, $T_J = 25^\circ\text{C}$

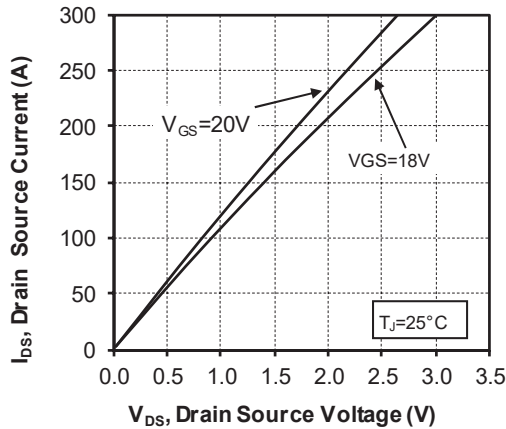


Figure 1-3. Output Characteristics, $T_J = 175^\circ\text{C}$

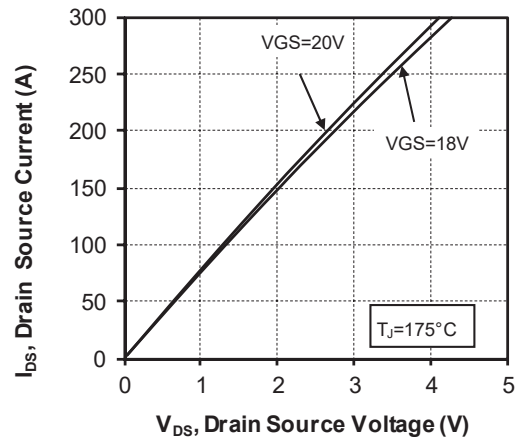


Figure 1-4. Normalized $R_{DS(on)}$ vs. Temperature

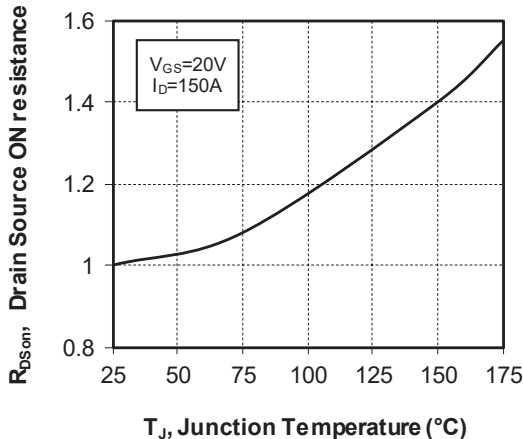


Figure 1-5. Transfer Characteristics

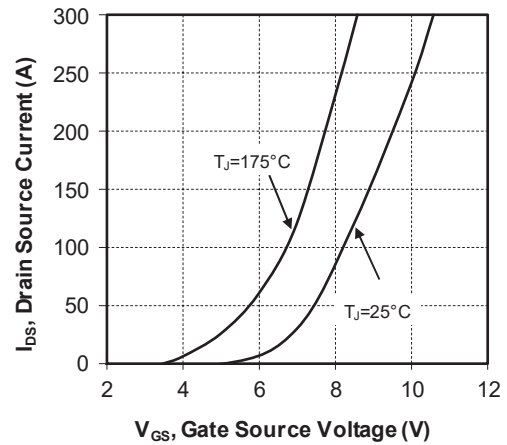


Figure 1-6. Switching Energy vs. Current

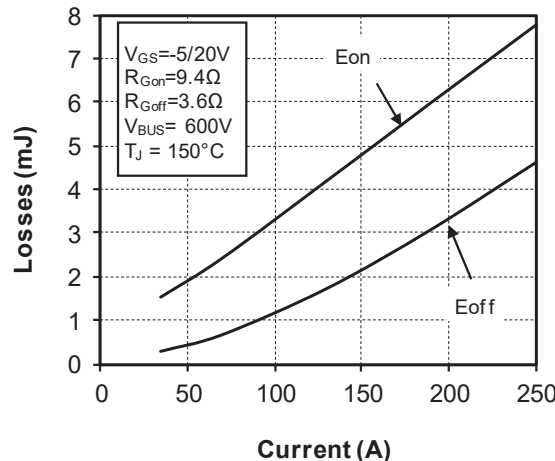


Figure 1-7. Switching Energy vs. Rg

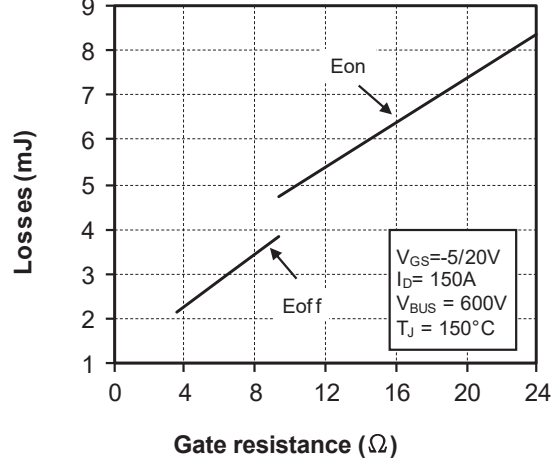


Figure 1-8. Capacitance vs. Drain Source Voltage

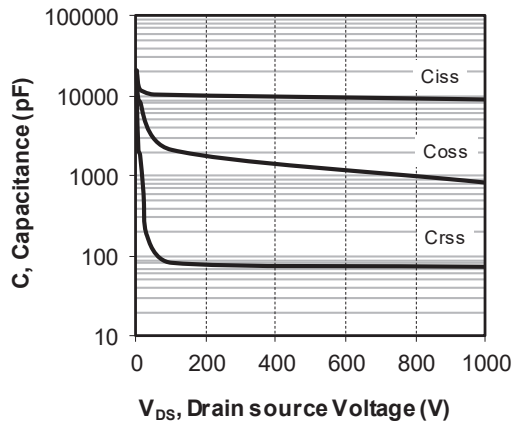


Figure 1-9. Gate Charge vs. Gate Source Voltage

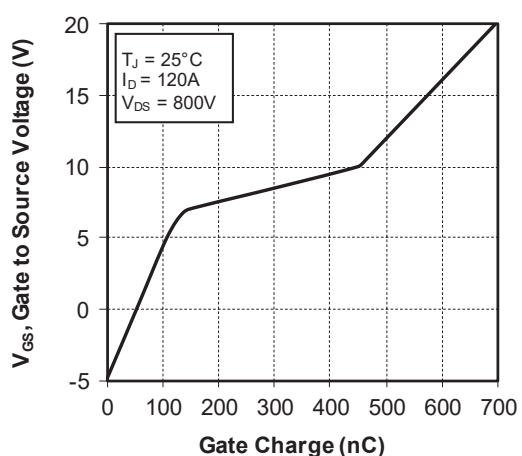


Figure 1-10. Body Diode Characteristics, $T_J = 25^\circ\text{C}$

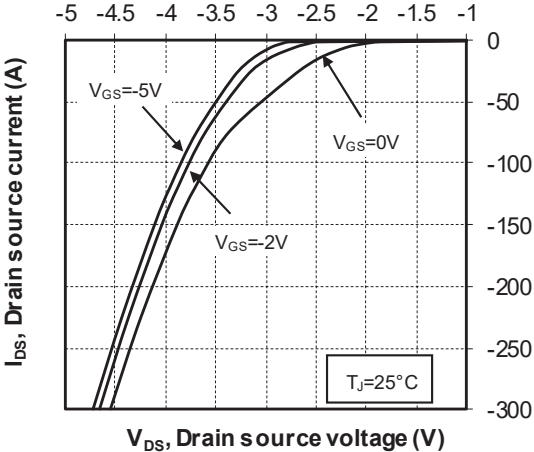


Figure 1-11. 3rd Quadrant Characteristics, $T_J = 25^\circ\text{C}$

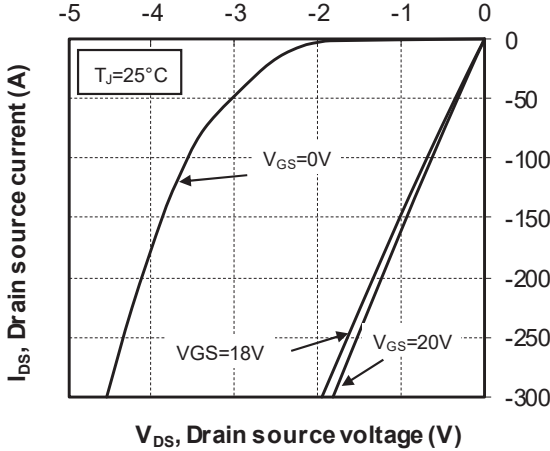


Figure 1-12. Body Diode Characteristics, $T_J = 175^\circ\text{C}$

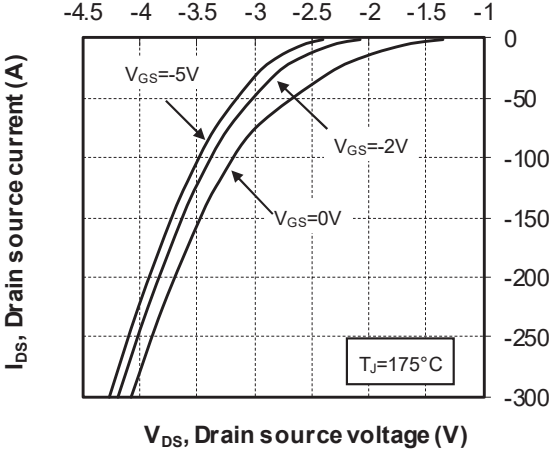


Figure 1-13. 3rd Quadrant Characteristics, $T_J = 175^\circ\text{C}$

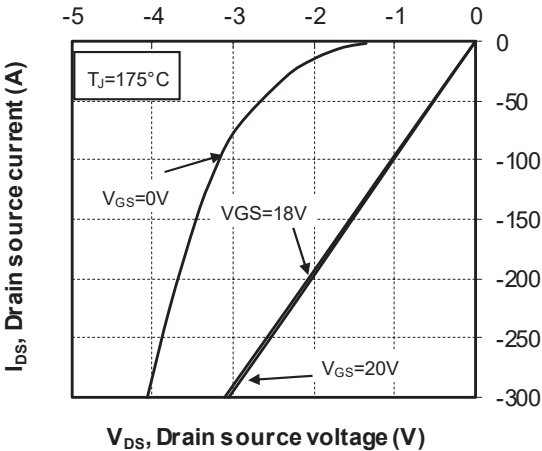
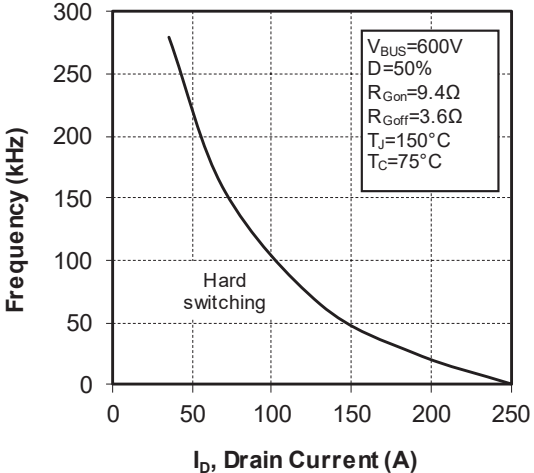


Figure 1-14. Operating Frequency vs Drain Current



3. Revision History

Revision	Date	Description
A	06/2022	Initial Release

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